TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX07F,TC74LCX07FN,TC74LCX07FT,TC74LCX07FK

Low-Voltage HEX Buffer with 5-V Tolerant Inputs and Outputs (open drain)

The TC74LCX07F/FN/FT/FK is a high-performance CMOS buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The TC74LCX07 has high performance MOS N-channel transistor. (open-drain outputs) $\,$

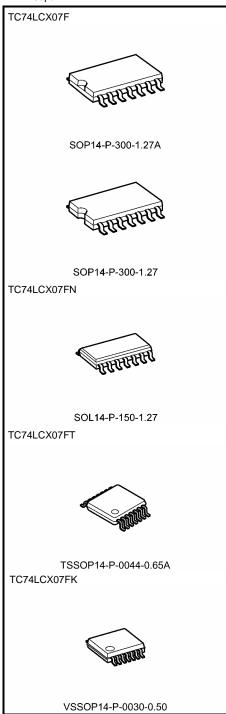
The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pz} = 3.7 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: IOL = 24 mA (min) (VCC = 3.0 V)
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- · Open-drain outputs
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 07 type

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

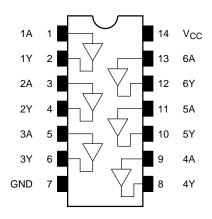
 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

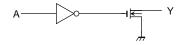
4.0	1	1 0	2	41/
1A -	3	1 ⊻	4	1Y
2A -	5			2Y
3A -	9			3Y
4A -	11			4Y
5A - 6A -	13		12	5Y 6Y
٠, ١				٠.

Truth Table

Inputs	Outputs
Α	Y
L	L
Н	Z

Z: High impedance

Systm Diagram (per gate)



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	V
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	-50 (Note 4)	mA
DC output current	I _{OUT}	50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Note 2: Output in OFF state

Note 3: Low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: V_{OUT} < GND

2006-02-01



Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit		
Power supply voltage	V _{CC}	2.0 to 3.6	V		
rower supply voltage	VCC	1.5 to 3.6 (Note 2)	V		
Input voltage	V _{IN}	0 to 5.5	V		
Output voltage	M	0 to 5.5 (Note 3)	V		
Output voltage	Vout	0 to V _{CC} (Note 4)	V		
Output current	lo	24 (Note 5)	mA		
Output current	loL	12 (Note 6)	IIIA		
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: Low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Symbol Test Condition		1	- Min	Max	Unit
		-,			V _{CC} (V)			
Input voltage	H-level	V _{IH}	_		2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}		_	2.7 to 3.6	_	0.8	v
			$V_{IN} = V_{IL}$	$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2	
Output voltage	L-level	VOI		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
Output voltage	L-level	VOL		$I_{OL} = 16 \text{ mA}$	3.0		0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
Output OFF state current		I _{OZ}	$V_{IN} = V_{IH}$, $V_{OUT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
Power-off leakage current		loff	V _{IN} /V _{OUT} = 5.5 V		0		10.0	μΑ
Quiescent supply c	urrent	1	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	10.0	
Quiescent supply c	unciii	lcc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±10.0	μΑ
Increase in Icc per input		Δl _{CC}	$V_{IH} = V_{CC} - 0.6$		2.7 to 3.6		500	



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Output anable time	4	Figure 1, Figure 2	2.7	1.0	4.4	- ns
Output enable time	t _{pZL}		3.3 ± 0.3	0.8	3.7	
Output disable time	t _{pLZ}	Figure 1, Figure 2	2.7	1.0	4.4	ns
Output disable time			3.3 ± 0.3	0.8	3.7	
Output to output skew	t _{osZL}	(Note)	2.7	_	_	ns
Cutput to output skew			3.3 ± 0.3	_	1.0	113

Note:

Parameter guaranteed by design.

 $(t_{OSZL} = |t_{pZLm} - t_{pZLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic VOL	V _{OLV}	$V_{IH}=3.3~V,~V_{IL}=0~V$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}			3.3	7	pF
Output capacitance	C _{OUT}	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	lote)	3.3	5	рF

Note:

C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/6 (per gate)$



AC Test Circuit

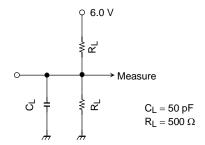


Figure 1

AC Waveform

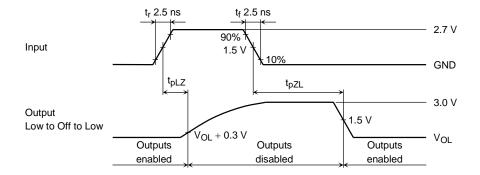
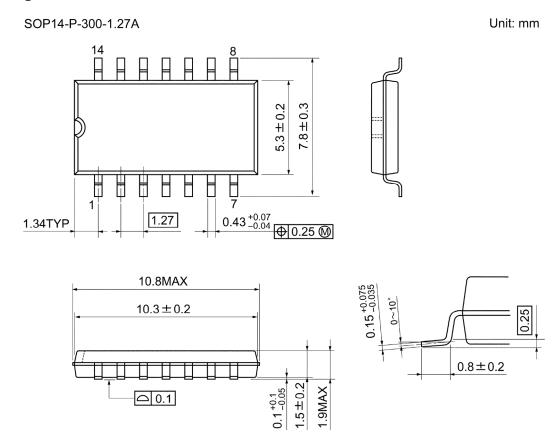
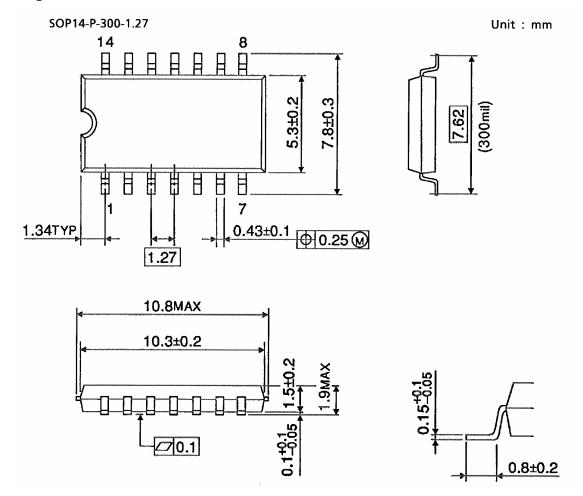


Figure 2 t_{pLZ} , t_{pZL}



Weight: 0.18 g (typ.)



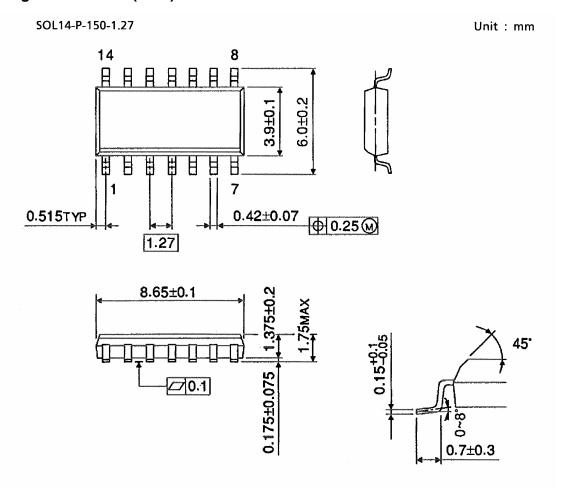


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Weight: 0.18 g (typ.)



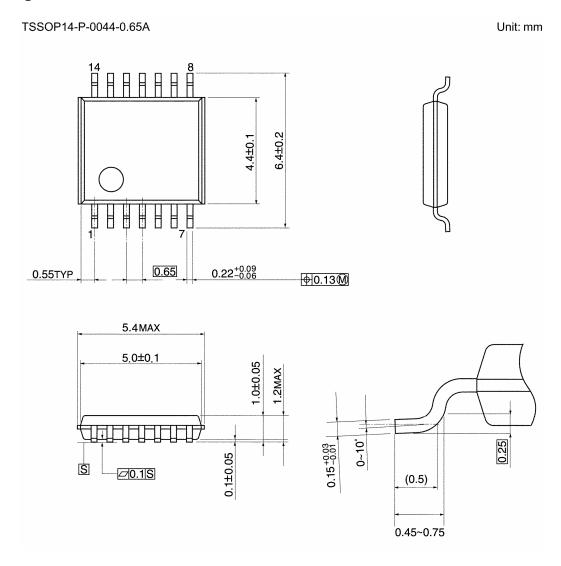
Package Dimensions (Note)



Note: This package is not available in japan.

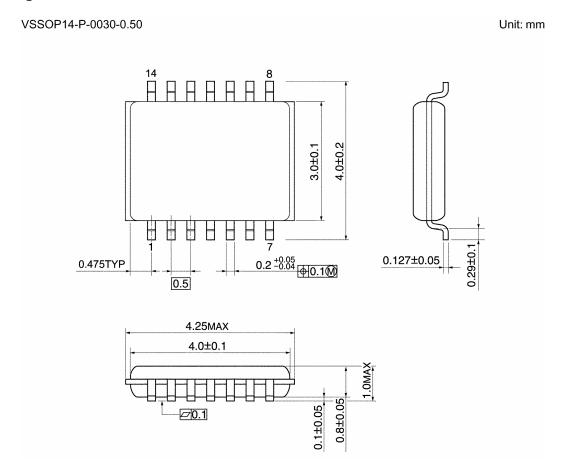
Weight: 0.12 g (typ.)





Weight: 0.06 g (typ.)





Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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